NSN 5962-01-251-8925

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View Online at https://aerobasegroup.com/nsn/5962-01-251-8925

| Body | Length: |
|------|---------|
| | |

Between 0.342 inches and 0.358 inches

Body Width:

Between 0.342 inches and 0.358 inches

Body Height:

Between 0.064 inches and 0.100 inches

Maximum Power Dissipation Rating:

500.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

High speed and monolithic and hermetically sealed

Inclosure Material:

Ceramic

Inclosure Configuration:

Leadless flat pack

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

Quad 2 input

Design Function And Quantity:

4 gate, nand

Case Outline Source And Designator:

C-2 mil-m-38510

Current Rating Per Characteristic:

25.00 milliamperes forward current, peak total value not applicable

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Time Rating Per Chacteristic:

150.00 nanoseconds propagation delay time, low to high level output and 150.00 nanoseconds propagation delay time, high to low level output

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

20 leadless

Shelf Life:

N/a

Unit Of Measure:

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